MSCDC50X1701AG Datasheet SiC Diode 3 Phase Bridge Power Module

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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

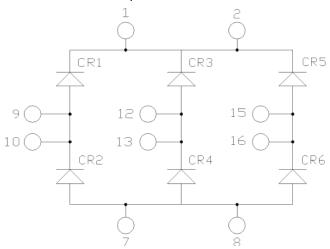
1.1 Revision 1.0

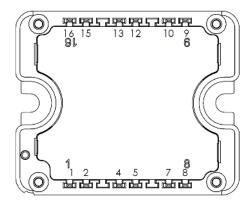
Revision 1.0 was published in December 2019. It is the first publication of this document.



2 Product Overview

This section shows the product overview of the MSCDC50X1701AG device.





All multiple inputs and outputs must be shorted together

1/2; 7/8; 9/10; 12/13; 15/16

All ratings at Tj = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.

2.1 Features

The following are key features of the MSCDC50X1701AG device:

- Silicon Carbide (SiC) Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF
- High blocking voltage
- Very low stray inductance
- Aluminum nitride (AIN) substrate for improved thermal performance



2.2 Benefits

The following are benefits of the MSCDC50X1701AG device:

- Outstanding performance at high frequency operation
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low profile
- RoHS compliant

2.3 Applications

The MSCDC50X701AG device is designed for the following applications:

- Welding converters
- Switched-mode power supplies
- Uninterruptible power supplies
- Battery DC power supply



3 Electrical Specifications

This section shows the electrical specifications of the MSCDC50X1701AG device.

3.1 Absolute Maximum Ratings

The following tables show the absolute maximum ratings per SiC diode and thermal and package characteristics of the MSCDC50X1701AG device.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter		Max Ratings	Unit
V _{RRM}	Repetitive peak reverse voltage		1700	V
I _F	DC forward current	T _C = 125 °C	50	Α

Table 2 • Thermal and Package Characteristics

Symbol	Characteristics		Min	Max	Unit	
V _{ISOL}	RMS isolation voltage, any terminal to case t =1 minute, 50 Hz/60 Hz			4000		V
T _J	Operating junction temperature range			-40	175	°C
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _{Jmax} –25	
T _{STG}	Storage temperature range			-40	125	
T _C	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package weight				80	g

3.2 Electrical Performance

The following table shows the electrical characteristics per SiC diode of the MSCDC50X1701AG device.

Table 3 • Electrical Characteristics

Symbol	Characteristics	Test Conditions		Min	Тур	Max	Unit
V _F	Diode forward voltage	I _F = 50 A	T _j = 25 °C		1.5	1.8	V
			T _j = 175 °C		2		
I _{RM}	Reverse leakage current	V _R = 1700 V	T _j = 25 °C		50	200	μΑ
			T _j = 175 °C		250		



Symbol	Characteristics	Test Conditions	Min	Тур	Max	Unit
Q _C	Total capacitive charge	V _R = 900 V		410		nC
С	Total capacitance	f = 1 MHz, V _R = 600 V		300		pF
		f = 1 MHz, V _R = 900 V		250		
R _{thJC}	Junction-to-case thermal resistance				0.32	°C/W

3.3 Typical Performance Curves

This section shows the typical performance curves of the MSCDC50X1701AG device.

Figure 1 • Maximum Transient Thermal Impedance

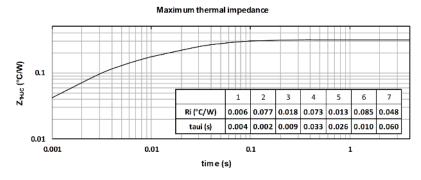


Figure 2 ● Forward Current vs. Forward Voltage

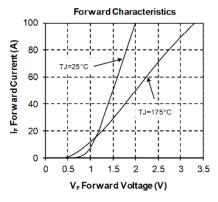
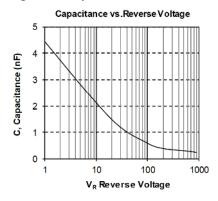


Figure 3 • Capacitance vs. Reverse Voltage





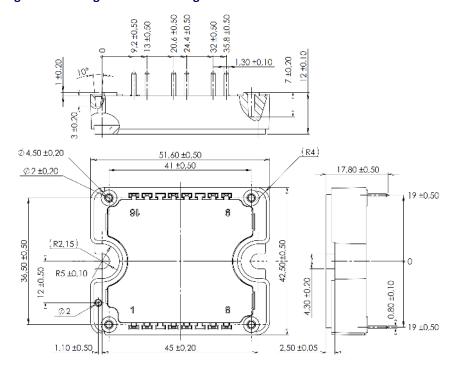
4 Package Specifications

This section shows the package specifications for the MSCDC50X1701AG device.

4.1 Package Outline Drawing

The following image illustrates the package outline of MSCDC50X1701AG device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing







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